

*Preliminary Specifications Subject to Change without Notice*

## DESCRIPTION

JW1985 is an ultra-high-voltage 3-string linear constant-power LED driver with a maximum input voltage of 700V, which is suitable for driving high-voltage low-current LED loads. The application solution has very few external components and compact layout, and can be easily and flexibly applied to various small-size or flat LED products. JW1985 greatly improved the power factor and THD of the system (meeting the IEC61000-3-2 standard). At the same time, the simple linear drive method does not require magnetic components, which can effectively avoid the problem of EMI.

In order to prevent the IC from overheating, the JW1985 integrates temperature control function. When temperature inside chip exceeds  $T_{OTP}$ , JW1985 decreases LED current, which can help chip cooling.

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## FEATURES

- Excellent line regulation
- Input constant power
- $\pm 5\%$  output current accuracy
- Multiple ICs can be used in parallel to meet large current output
- High power factor and ultra-low THD
- Very few external components
- Over temperature protection function
- ESOP8 package

## APPLICATIONS

- LED Bulb Light
- LED Flood Light
- Other LED Lights

TYPICAL APPLICATION

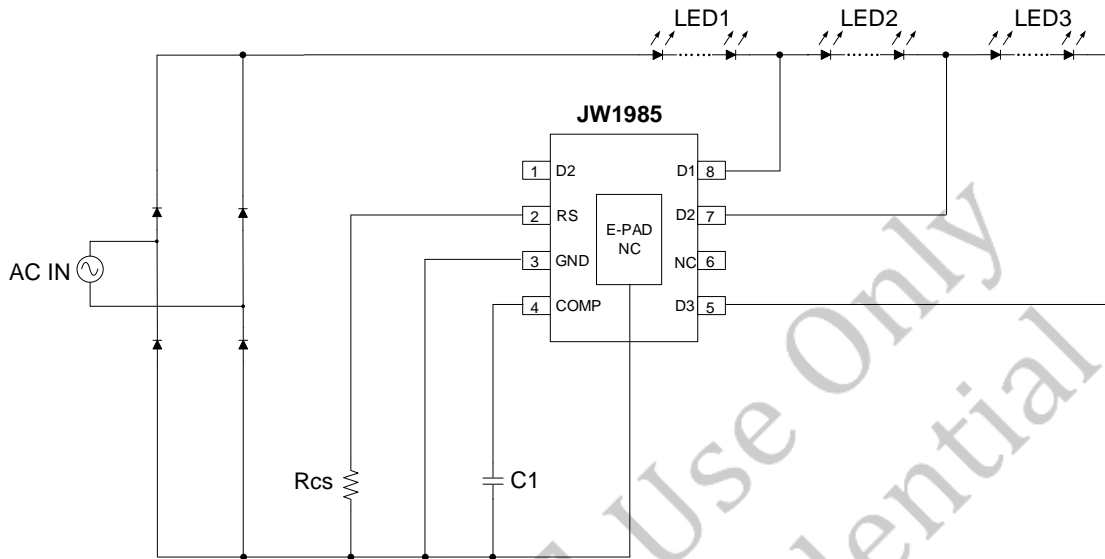


FIG.1 Schematic Diagram of Flood Light

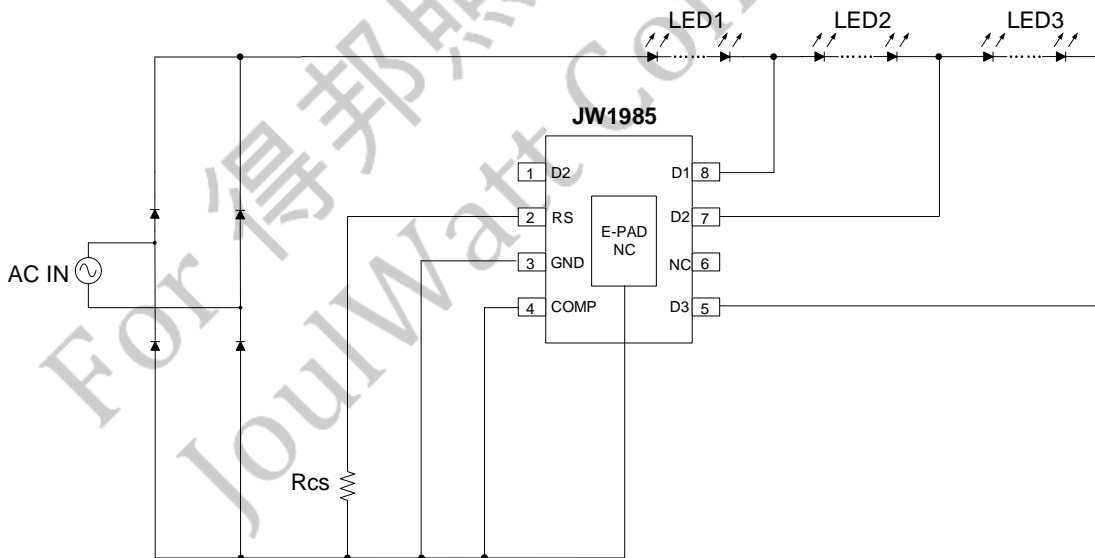
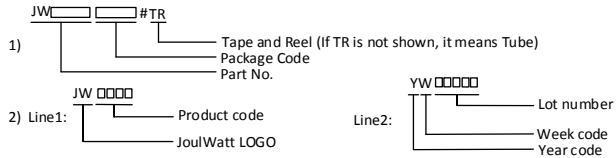


FIG.2 Schematic Diagram of Indian Bulb Light

**ORDER INFORMATION**

DEVICE <sup>1)</sup>	PACKAGE	TOP MARKING <sup>2)</sup>	ENVIRONMENTAL <sup>3)</sup>
JW1985ESOP#TR	ESOP8	JW1985 YW□□□□□	Green

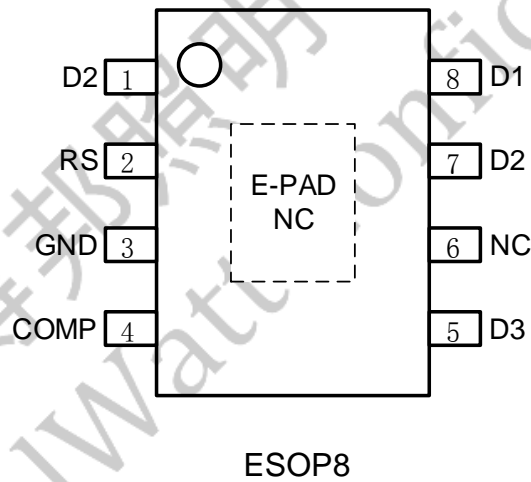
**Notes:**



3) All JoulWatt products are packaged with Pb-free and Halogen-free materials and compliant to RoHS standards.

**PIN CONFIGURATION**

**TOP VIEW**



**ABSOLUTE MAXIMUM RATING<sup>1)</sup>**

D1 D2.....	-0.3V to +700V
D3.....	-0.3V to +650V
COMP.....	-0.3V to +5.5V
RS.....	-0.3V to +5.5V
Junction Temperature <sup>2)3)</sup> .....	-40°C to +150°C
Storage Temperature .....	-40°C to +150°C

**RECOMMENDED OPERATING CONDITIONS**

D1 D2.....	-0.3V to +630V
D3.....	-0.3V to +600V
Junction Temperature (T <sub>J</sub> ) .....	-40°C to 125°C

**THERMAL PERFORMANCE<sup>4)</sup>**

	$\theta_{JA}$	$\theta_{JC}$
ESOP8.....	50.....	10°C/W

**Note:**

- 1) Exceeding these ratings may damage the device. These stress ratings do not imply function operation of the device at any other conditions beyond those indicated under RECOMMENDED OPERATING CONDITIONS.
- 2) The JW1985 includes thermal protection that is intended to protect the device in overload conditions. Continuous operation over the specified absolute maximum operating junction temperature may damage the device.
- 3) The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on JESD51-7, 4-layer PCB.

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## ELECTRICAL CHARACTERISTICS

$T_a = 25\text{ }^\circ\text{C}$ , unless otherwise stated.

*Advance Information, not production data, subject to change without notice.*

Item	Symbol	Condition	Min.	Typ.	Max.	Unit.
<b>Power Supply</b>						
Quiescent Current	$I_Q$	VD1=VD3=100V, COMP =100nF		190	250	$\mu\text{A}$
<b>Reference</b>						
RS Voltage_1	$V_{RS1}$	VD1=VD3=100V,COMP =100nF	466	491	516	mV
RS Voltage_2	$V_{RS2}$	VD1=VD3=150V, COMP =100nF	323	341	360	mV
RS Voltage_3	$V_{RS3}$	VD1=VD3=100V, COMP to GND	414	437	460	mV
RS Voltage_4	$V_{RS4}$	VD1=VD3=200V, COMP to GND	631	665	699	mV
<b>Protections</b>						
OTP Point <sup>5)</sup>	$T_{OTP}$		135	145	155	$^\circ\text{C}$
OTP Slope_1 <sup>5)</sup>	$K_{T_1}$	COMP=100nF		-35%		$10^\circ\text{C}$
OTP Slope_2 <sup>5)</sup>	$K_{T_2}$	COMP to GND		-20%		$10^\circ\text{C}$
D1 Over Voltage Protection <sup>5)</sup>	$D1_{ovp}$	COMP=100nF	330	360	390	V
<b>Power MOSFET</b>						
BV of D1	$V_{BV_1}$	$I_d=250\mu\text{A}$	700			V
BV of D2	$V_{BV_2}$	$I_d=250\mu\text{A}$	700			V
BV of D3	$V_{BV_3}$	$I_d=250\mu\text{A}$	650			V
Saturation Current of D1	$I_{SAT_1}$	$V_G=5V, V_{out1}=20V$	58			mA
Saturation Current of D2	$I_{SAT_2}$	$V_G=5V, V_{out2}=20V$	98			mA
Saturation Current of D3	$I_{SAT_3}$	$V_G=5V, V_{out2}=20V$	128			mA

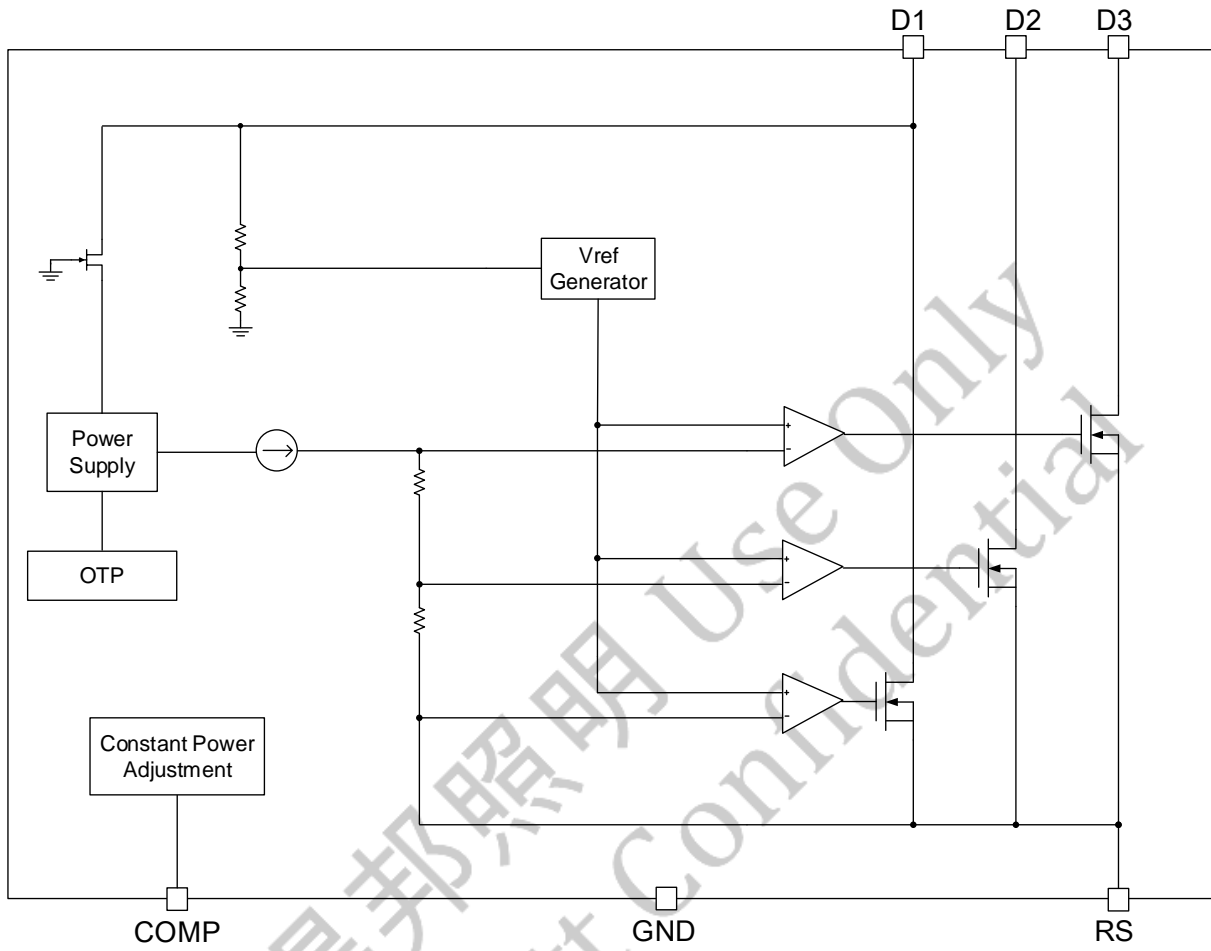
**Note**

5) Guaranteed by design.

## PIN DESCRIPTION

Pin ESOP8	Name	Description
1	D2	DRAIN of the Channel 2(CH2)
2	RS	Current sensing pin
3	GND	Chip ground
4	COMP	Constant power adjustment
5	D3	DRAIN of the Channel 3(CH3)
6	NC	Not Connected
7	D2	DRAIN of the Channel 2(CH2)
8	D1	DRAIN of the Channel 1(CH1)
E-PAD	NC	Not Connected

BLOCK DIAGRAM



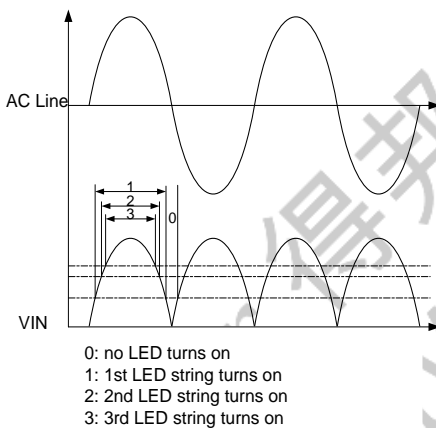
## FUNCTIONAL DESCRIPTION

JW1985 is an ultra-high-voltage 3-string linear LED driver for direct line operation.

### Theory of Operation

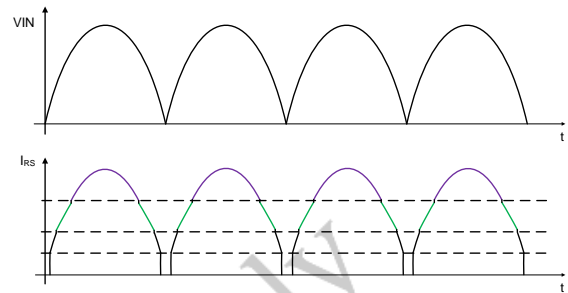
The input is the rectified voltage from AC mains by bridge rectifier. When VIN is higher than the forward voltage of the 1<sup>st</sup> LED string, JW1985 can detect it and turn on the 1<sup>st</sup> MOSFET to lighten the 1<sup>st</sup> LED string. When VIN keeps increasing and exceeds the total forward voltage of the 1<sup>st</sup> and 2<sup>nd</sup> LED strings, JW1985 turns on the 2<sup>nd</sup> MOSFET to lighten the 1<sup>st</sup> and 2<sup>nd</sup> LED strings. In the same way, all LED strings are lightened as VIN increases.

During the VIN decrease, JW1985 shuts down the MOSFET as the reverse sequence.



### Sine Wave Current Control

The IC introduces BUS voltage into the linear IC to modulate the output LED current waveform, so that the input current has a sinusoidal waveform to achieve high PF value and ultra-low THD, which can meet the IEC6100-3-2 harmonic standard. The VIN voltage waveform and current waveform are shown below.



### LED Current Control

JW1985 adopts a mathematical calculation method for the LED current control. The input constant power can be set by COMP pin. Different constant power modes are realized by whether the COMP pin is grounded or not. When a capacitor about 100nF is connected to the COMP, the reference voltage can be calculated as:

$$V_{REF1}(\theta) \sim \frac{1.6V - 2.25 * \frac{1}{\pi} \int_0^{\pi} \frac{VD1(\theta)}{200} d(\theta) + \frac{VD1(\theta)}{200}}{2}$$

$$V_{REF2}(\theta) \sim \frac{1.6V + 10\mu A * 1.6K - 2.25 * \frac{1}{\pi} \int_0^{\pi} \frac{VD1(\theta)}{200} d(\theta) + \frac{VD1(\theta)}{200}}{2}$$

$$V_{REF3}(\theta) \sim \frac{1.6V + 10\mu A * 3.2K - 2.25 * \frac{1}{\pi} \int_0^{\pi} \frac{VD1(\theta)}{200} d(\theta) + \frac{VD1(\theta)}{200}}{2}$$

Where

$V_{REFn}(\theta)$  is the reference voltage;

$VD1(\theta)$  is Drain voltage of the Channel 1.

When COMP short to GND pin, can be calculated as:

$$V_{REF1}(\theta)$$



$$V_{REF2}(\theta) = \frac{0.4V - 4 * (\frac{VD1(\theta)}{200} - 1.0) + \frac{VD1(\theta)}{200}}{2}$$

$V_{REF2}(\theta)$

$$V_{REF3}(\theta) = \frac{0.4V + 10\mu A * 1.6K - 4 * (\frac{VD1(\theta)}{200} - 1.0) + \frac{VD1(\theta)}{200}}{2}$$

$V_{REF3}(\theta)$

$$V_{REFn}(\theta) = \frac{0.4V + 10\mu A * 3.2K - 4 * (\frac{VD1(\theta)}{200} - 1.0) + \frac{VD1(\theta)}{200}}{2}$$

Where

$V_{REFn}(\theta)$  is the reference voltage;

$VD1(\theta)$  is Drain voltage of the Channel 1.

The instantaneous current of LED is calculated as follows:

$$I_{LED}(\theta) = V_{REFn}(\theta) / R_{CS}$$

Where

$I_{LED}(\theta)$  is the instantaneous current;

$V_{REFn}(\theta)$  is the reference voltage;

$R_{CS}$  is the current sensing resistor connected between RS pin and GND pin.

### Over Temperature Protection

JW1985 incorporates a thermal protection mechanism. When the internal junction temperature is higher than  $T_{OTP}$ , the internal reference voltage decreases by  $K_T$ , and the output current decreases.

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**REFERENCE DESIGN**

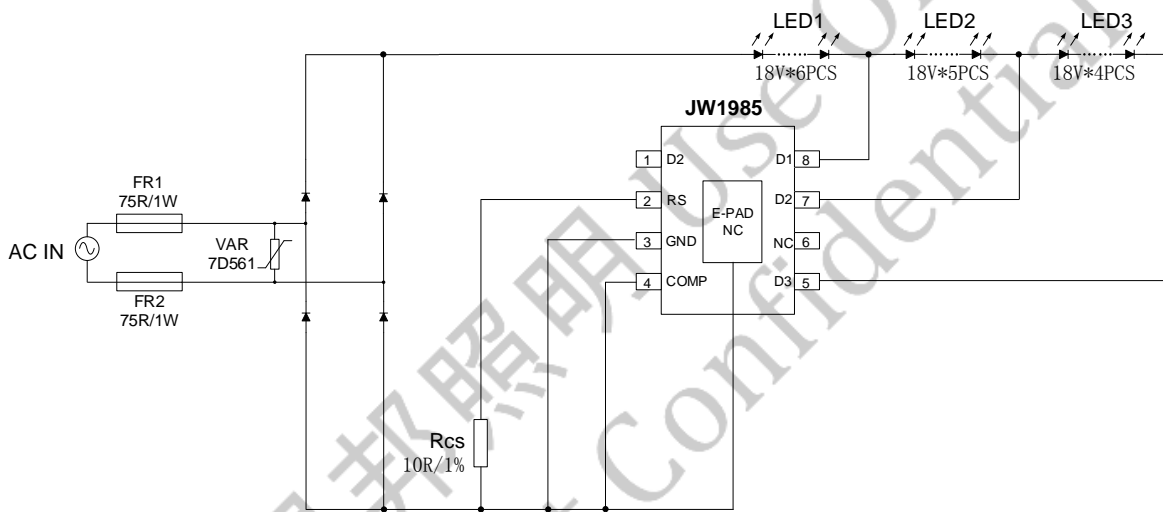
*Note: Information in the following reference design sections is not part of JoulWatt component specification. Customers are responsible for determining suitability of components chosen for their purposes and should validate their design implementation to make sure the proper system functionality.*

**Reference 1: Indian Bulb**

V<sub>IN</sub>: 100V~300V

V<sub>OUT</sub>: 18V\*15PCS, LED Voltage Ratio: 6:5:4

I<sub>LED</sub>: ~38mA

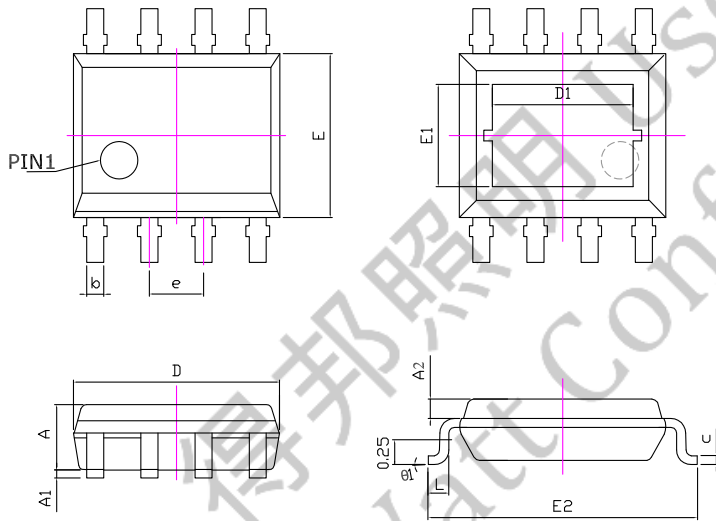




PACKAGE OUTLINE

ESOP8

UNIT : mm



SYMBOL	MIN	NOM	MAX
A	1.35	1.45	1.55
A1	0.00	0.05	0.10
A2	0.60	0.70	0.80
D	4.80	4.90	5.00
D1	3.20	3.30	3.40
E	3.80	3.90	4.00
E1	2.30	2.40	2.50
E2	5.80	6.00	6.20
L	0.45	0.60	0.75
b	0.33	0.40	0.47
c	0.17	0.203	0.25
e	1.27 BSC		
e1	0°	-	8°

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